FAIRCHILD

SEMICONDUCTOR TM

KSB546

TV Vertical Deflection Output

- Collector-Base Voltage : V_{CBO} = -200V Collector Current : I_C = -2A Collector Dissipation : P_C = 25W (T_C =25°C)
- Complement to KSD401



1.Base 2.Collector 3.Emitter

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

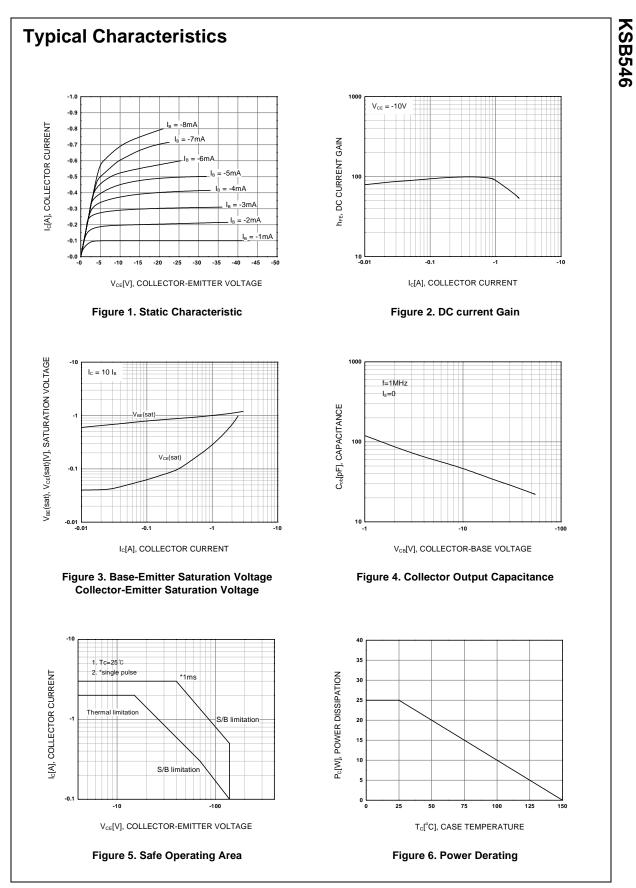
Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	- 200	V
V _{CEO}	Collector-Emitter Voltage	- 150	V
V _{EBO}	Emitter-Base Voltage	- 5	V
I _C	Collector Current(DC)Y	- 2	А
P _C	Collector Dissipation (T _C =25°C)	25	W
Т _Ј	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C = - 500μA, I _E = 0	- 200			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = - 10mA, I _B = 0	- 150			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = - 500uA, I _C = 0	- 5			V
I _{CBO}	Collector Cut-off Current	V _{CB} = - 150V, I _E = 0			- 50	μΑ
h _{FE}	DC Current Gain	V _{CE} = - 10V, I _E = - 0.4A	40		240	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = - 500mA, I _B = - 50mA			- 1	V
f _T	Current Gain Bandwidth Product	V _{CE} = - 10V, I _C = - 0.4A		5		MHz

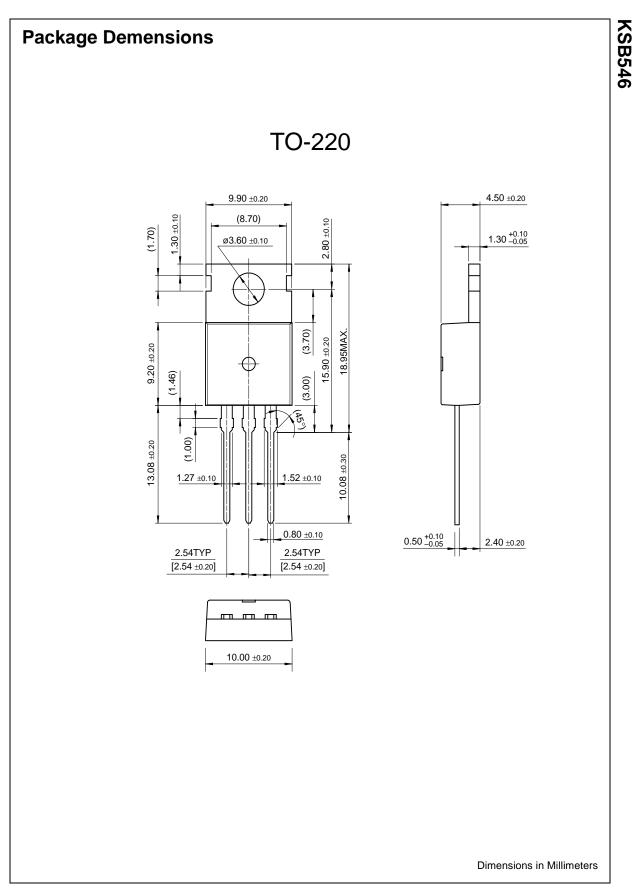
h_{FE} Classification

Classification	R	0	Y
h _{FE}	40 ~ 80	70 ~ 140	120 ~ 240



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